

Schottky Diode Gen ²

preliminary

$$V_{RRM} = 200V$$

$$I_{FAV} = 15A$$

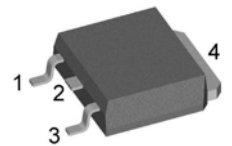
$$V_F = 0.78V$$

High Performance Schottky Diode
Low Loss and Soft Recovery
Single Diode

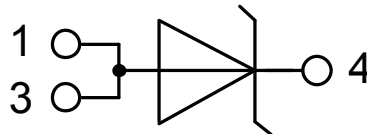
Part number

DSA15IM200UC

Marking on Product: SFMAUI



Backside: cathode

**Features / Advantages:**

- Very low V_f
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-252 (DPak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

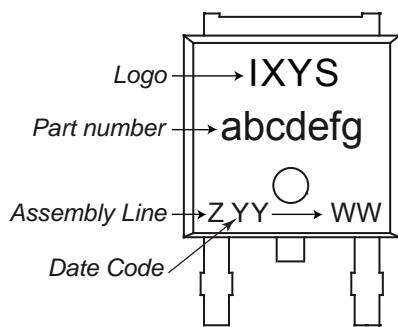
Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage					200	V
V_{RRM}	max. repetitive reverse blocking voltage					200	V
I_R	reverse current, drain current	$V_R = 200$ V		$T_{VJ} = 25^\circ\text{C}$		250	μA
		$V_R = 200$ V		$T_{VJ} = 125^\circ\text{C}$		2.5	mA
V_F	forward voltage drop	$I_F = 15$ A		$T_{VJ} = 25^\circ\text{C}$		0.94	V
		$I_F = 30$ A				1.10	V
		$I_F = 15$ A		$T_{VJ} = 125^\circ\text{C}$		0.78	V
		$I_F = 30$ A				0.95	V
I_{FAV}	average forward current	$T_C = 150^\circ\text{C}$	rectangular	$T_{VJ} = 175^\circ\text{C}$		15	A
V_{FO}	threshold voltage	} for power loss calculation only		$T_{VJ} = 175^\circ\text{C}$		0.53	V
r_F	slope resistance					10.8	m Ω
R_{thJC}	thermal resistance junction to case					2	K/W
R_{thCH}	thermal resistance case to heatsink				0.50		K/W
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		75	W
I_{FSM}	max. forward surge current	$t = 10$ ms; (50 Hz), sine; $V_R = 0$ V		$T_{VJ} = 45^\circ\text{C}$		200	A
C_J	junction capacitance	$V_R = 24$ V	$f = 1$ MHz	$T_{VJ} = 25^\circ\text{C}$		67	pF

preliminary

Package TO-252 (DPak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			20	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				0.3		g
F_C	mounting force with clip		20		60	N

¹⁾ I_{RMS} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

Product Marking



Part number

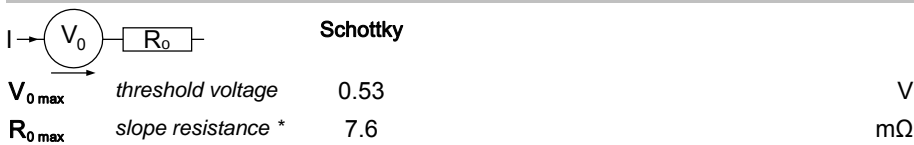
- D = Diode
- S = Schottky Diode
- A = low VF
- 15 = Current Rating [A]
- IM = Single Diode
- 200 = Reverse Voltage [V]
- UC = TO-252AA (DPak)

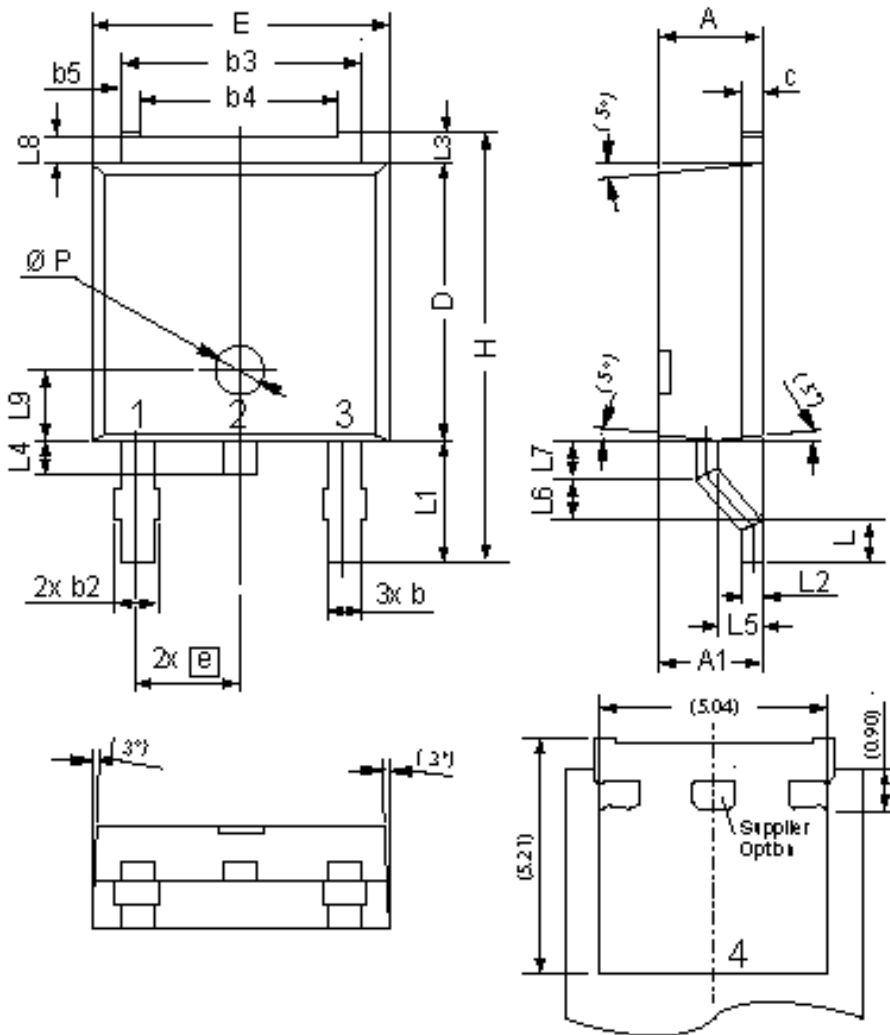
Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA15IM200UC	SFMAUI	Tape & Reel	2500	510408

Equivalent Circuits for Simulation

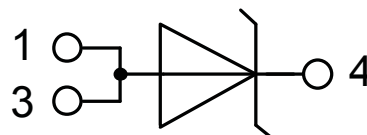
* on die level

$T_{VJ} = 175\text{ °C}$



Outlines TO-252 (DPak)


Dim	Millimeters		Inches	
	min	max	min	max
A	2.20	2.40	0.087	0.094
A1	2.10	2.50	0.083	0.098
b	0.66	0.86	0.026	0.034
b2	-	0.96	-	0.038
b3	5.04	5.64	0.198	0.222
b4	4.34 BSC		0.171 BSC	
b5	0.50 BSC		0.020 BSC	
c	0.40	0.86	0.016	0.034
D	5.90	6.30	0.232	0.248
E	6.40	6.80	0.252	0.268
e	2.10	2.50	0.083	0.098
H	9.20	10.10	0.362	0.398
L	0.55	1.28	0.022	0.050
L1	2.50	2.90	0.098	0.114
L2	0.40	0.60	0.016	0.024
L3	0.50	0.90	0.020	0.035
L4	0.60	1.00	0.024	0.039
L5	0.82	1.22	0.032	0.048
L6	0.79	0.99	0.031	0.039
L7	0.81	1.01	0.032	0.040
L8	0.40	0.80	0.016	0.031
L9	1.50 BSC		0.059 BSC	
Ø P	1.00 BSC		0.039 BSC	



Schottky

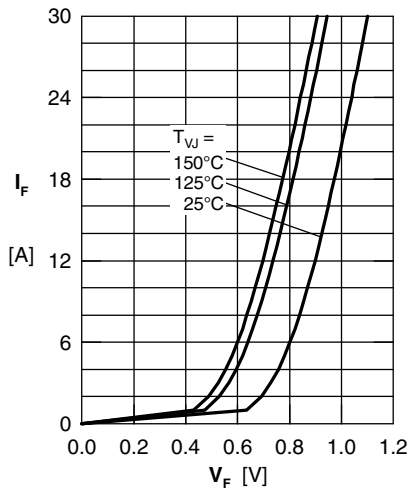


Fig. 1 Maximum forward voltage drop characteristics

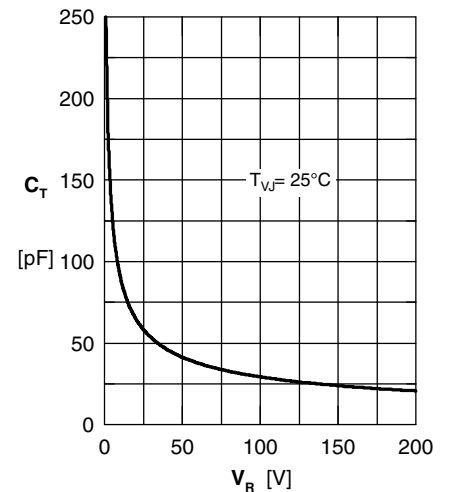


Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

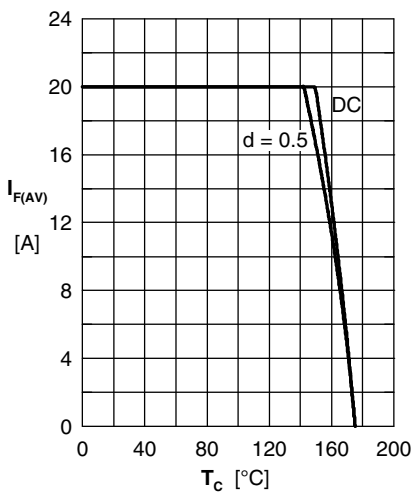


Fig. 4 Avg: forward current $I_{F(AV)}$ vs. case temperature T_C

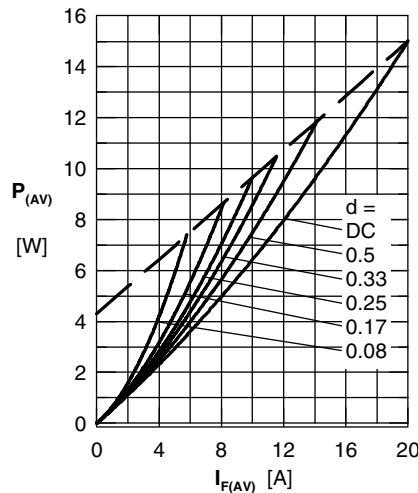


Fig. 5 Forward power loss characteristics

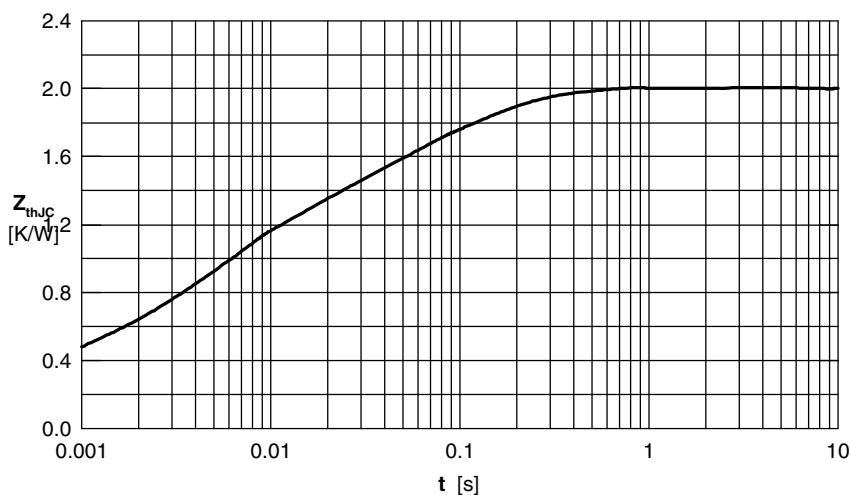


Fig. 6 Transient thermal impedance junction to case